11-17-2003



Attorney Docket No.: 108

2. Name and address of receiving party(ies)  Name: Winbond Electronics Corporation  Street Address: No. 4, Creation Road III Science-Based Industrial Park  City: Hsin Chu State: Taiwan, Republic of China  Additional names and addresses attached?   Yes   No
Name: Winbond Electronics Corporation  Street Address: No. 4, Creation Road III Science-Based Industrial Park  City: Hsin Chu State: Taiwan, Republic of China  Additional names and addresses attached?
Street Address: No. 4, Creation Road III Science-Based Industrial Park City: Hsin Chu State: Taiwan, Republic of China Additional names and addresses attached?
Science-Based Industrial Park  City: Hsin Chu State: Taiwan, Republic of China  Additional names and addresses attached?
Additional names and addresses attached?
☐ Yes
e execution date of the application is: n/a
. Patent No(s):
] No
6. Total number of applications and patents involved 1
7. Total fee (37 CFR 3.41): \$40.00
☐ Enclosed ☐ Charge Fees to Deposit Account
Charge any additional fees associated with this paper during the pendency of this application, or credit any overpayment, to deposit account.
8 Deposit account number: 50-1229
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**PATENT REEL: 014686 FRAME: 0854** 

## ASSIGNMENT OF PATENT APPLICATION

WHEREAS, SHENG-HSIUNG HSUEH of 6610 Graystone Meadow Circle, San Jose, CA 95120; GANSHU BEN LEE of 3635 De Soto Avenue, Santa Clara, CA 95051; LOC BAI HOANG of 5253 Rooster Drive, San Jose, CA 95136; CHUN-MAI LIU of 5896 Castano Drive, San Jose, CA 95129; and ALBERT V. KORDESCH of 6887 Goldpine Court, San Jose, CA 95120 hereinafter referred to as "Assignor," are the inventors of the invention described and set forth in the below-identified application for United States Letters Patent:

Title of Invention: DUAL REFERENCE CELL FOR SPLIT-GATE NONVOLATILE SEMICONDUCTOR MEMORY Application No.: 10/126,450 Filing Date: April 19, 2002 Dates of execution of the Declaration: ; and WHEREAS, Winbond Electronics Corporation, located at No. 4, Creation Road III, Sciencebased Industrial Park, Hsin Chu, Taiwan, Republic of China, hereinafter referred to as "ASSIGNEE," is desirous of acquiring an interest in the invention and application and in any U.S. Letters Patent and Registrations which may be granted on the same. For good and valuable consideration, receipt of which is hereby acknowledged by Assignors, Assignors have assigned, and by these presents do assign to Assignee all right, title and interest in and to the invention and application and to all foreign counterparts (including patent, utility model and industrial designs), and in and to any Letters Patent and Registrations which may hereafter be granted on the same in the United States and all countries throughout the world, and to claim the priority from the application as provided by the Paris Convention. The right, title and interest is to be held and enjoyed by Assignee and Assignee's successors and assigns as fully and exclusively as it would have been held and enjoyed by Assignors had this Assignment not been made, for the full term of any Letters Patent and Registrations which may be granted thereon, or of any division, renewal, continuation in whole or in part, substitution, conversion, reissue, prolongation or extension thereof. Assignors further agree that they will, without charge to Assignee, but at Assignee's expense, (a) cooperate with Assignee in the prosecution of U.S. Patent applications and foreign counterparts on the invention and any improvements, (b) execute, verify, acknowledge and deliver all such further papers, including patent applications and instruments of transfer, and (c) perform such other acts as Assignee lawfully may request to obtain or maintain Letters Patent and Registrations for the invention and improvements in any and all countries, and to vest title thereto in Assignee, or Assignee's successors and assigns. Assignor hereby authorizes and requests DINH & ASSOCIATES, 2506 Ash Street, Palo Alto, CA 94306, to insert herein above the dates of execution of the Declaration, when known. IN TESTIMONY WHEREOF, Assignors have signed their names on the dates indicated. Inventor 1 Signature: \_\_\_\_\_\_ SHENG-HSIUNG HSUEH ee Date: 7-23-02 Date: \_\_\_\_\_ Inventor 3 Signature: \_\_\_\_\_ LOC BAO HOANG in Mai fri Date: 7-23-02

ALBERT V. KORDESCH

Inventor 4 Signature: \_\_\_

Inventor 5 Signature:

PATENT

## ASSIGNMENT OF PATENT APPLICATION

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ALBERT V. KORDESCH

**CHUN-MAI LIU** 

Inventor 4 Signature:

Date: AUG.02, 2002

## ASSIGNMENT OF PATENT APPLICATION

WHEREAS, SHENG-HSIUNG HSUEH of 6610 Graystone Meadow Circle, San Jose, CA 95120; GANSHU BEN LEE of 3635 De Soto Avenue, Santa Clara, CA 95051; LOC BADHOANG of 5253 Rooster Drive, San Jose, CA 95136; CHUN-MAI LIU of 5896 Castano Drive, San Jose, CA 95129; and ALBERT V. KORDESCH of 6887 Goldpine Court, San Jose, CA 95120 hereinafter referred to as "Assignor," are the inventors of the invention described and set forth in the below-identified application for United States Letters Patent:

BERT V. KORDESCH of 6887 Goldpine Court, San Jose, CA 95120 hereinafter referred to as "Asset the inventors of the invention described and set forth in the below-identified application for United ters Patent:

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Application No.: 10/126,450
Filing Date: April 19, 2002

Dates of execution of the Declaration: ; and

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For good and valuable consideration, receipt of which is hereby acknowledged by Assignors, Assignors have assigned, and by these presents do assign to Assignee all right, title and interest in and to the invention and application and to all foreign counterparts (including patent, utility model and industrial designs), and in and to any Letters Patent and Registrations which may hereafter be granted on the same in the United States and all countries throughout the world, and to claim the priority from the application as provided by the Paris Convention. The right, title and interest is to be held and enjoyed by Assignee and Assignee's successors and assigns as fully and exclusively as it would have been held and enjoyed by Assignors had this Assignment not been made, for the full term of any Letters Patent and Registrations which may be granted thereon, or of any division, renewal, continuation in whole or in part, substitution, conversion, reissue, prolongation or extension thereof.

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IN TESTIMONY WHEREOF, Assignors have signed their names on the dates indicated.

Inventor 1 Signature: _	SHENG-HSIUNG HSUEH	Date:
Inventor 2 Signature:	GANSHU BEN LEE	Date:
Inventor 3 Signature:	Loc Bao Hoang LOC BAO HOANG	Date: August 8th, 2002
Inventor 4 Signature: _	CHUN-MAI LIU	Date:
Inventor 5 Signature:	ALBERT V. KORDESCH	Date:

PATENT REEL: 014686 FRAME: 0857

## ASSIGNMENT OF PATENT APPLICATION

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Inventor 1 Signature:

| Date: | Date:

**RECORDED: 11/10/2003** 

PATENT REEL: 014686 FRAME: 0858